



# ULTRAFAST RECTIFIERS, High Efficiency 25A and 30A

High-Reliability screening available

### **DESCRIPTION**

The UES701(HR2) through UES703(HR2) series of ultrafast high-efficiency rectifiers is specifically designed for operation in power switching circuits operating at frequencies of 20 kHz or higher. The low thermal resistance and forward voltage drop of this series allows the user to replace larger DO-5 packaged devices in many applications. Microsemi also offers numerous other products to meet higher and lower power voltage regulation applications.



**DO-4 Package** 

Important: For the latest information, visit our website <a href="http://www.microsemi.com">http://www.microsemi.com</a>.

#### **FEATURES**

- Very low forward voltage (0.825 V @ I<sub>F</sub> = 25 A).
- Very fast recovery times (35-50 ns).
- Low thermal resistance.
- · High reliability screening option.
- Mechanically rugged.
- Both polarities available.
- RoHS compliant devices available by adding "e3" suffix (commercial grade only).

## **APPLICATIONS / BENEFITS**

- Power switching circuits 20 kHz and above with minimal parasitic switching losses.
- Catch diodes for switching regulators.
- Output rectifiers for high frequency square-wave inverters.
- Extremely robust in power cycling.
- High surge capability.
- Hermetically sealed.

### **MAXIMUM RATINGS**

Parameters/Test Conditions	Symbol	Value	Unit	
Junction and Storage Temperature	$T_J$ and $T_{STG}$	-55 to +175	°C	
Thermal Resistance Junction-to-Case	Rejc	1.5	°C/W	
Working Peak Reverse Voltage	UES701	$V_{RWM}$	50	V
	UES702		100	
	UES703		150	
Repetitive Peak Reverse Voltage	UES701	$V_{RRM}$	50	V
	UES702		100	
	UES703		150	
RMS Forward Current		I <sub>F(RMS)</sub>	40	Amps
Non-Repetitive Sinusoidal Surge Current (	I <sub>FSM</sub>	400	Amps	
Maximum Average DC Output Current @	Io	25	Amps	

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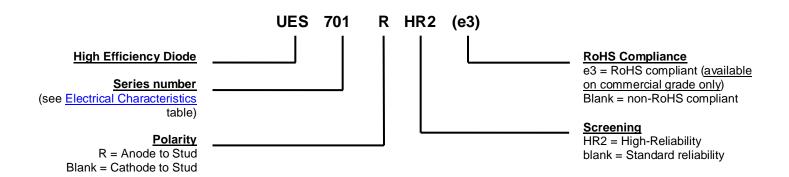
## **MECHANICAL and PACKAGING**

- CASE: Hermetically sealed metal and glass case body with 7/16 inch hex and 10-32 threaded stud.
- TERMINALS: Tin-lead plated or RoHS compliant matte-tin plating (commercial grade only) on nlckel.
- MARKING: Part number.
- WEIGHT: 10 grams (approximate).
- Maximum Stud Torque: 10 inch pounds.
- See Package Dimensions on last page.

# OPTIONAL HIGH RELIABILITY (HR2) SCREENING

SCREEN	MIL-STD-750 METHOD	CONDITIONS
High Temperature	1032	24 Hours @ T <sub>A</sub> = 150°C
2. Temperature Cycle	1051	F, 20 Cycles, -55 to +150 °C. No dwell required @ 25 °C, T > 10 min. @ extremes
3. Hermetic Seal		
a. Fine Leak	1071	H, Helium
b. Gross Leak		C, Liquid
4. Thermal Impedance	3101	
5. Interim Electrical Parameters	GO/NO GO	As applicable
6. High Temperature Reverse Bias	As Applicable	t= 48 hours, Tc = 125 °C with applicable
(HTRB)		bias conditions
7. Final Electrical Parameters	GO/NO GO	As applicable

## **PART NOMENCLATURE**



	SYMBOLS & DEFINITIONS					
Symbol	Definition					
I <sub>F</sub>	Forward Current: The forward current dc value, no alternating component.					
$I_{FSM}$	Maximum Forward Surge Current: The forward current, surge peak or rated forward surge current.					
Io	Average Rectified Output Current: The Output Current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave input and a 180 degree conduction angle.					
I <sub>R</sub>	Reverse Current: The maximum reverse (leakage) current that will flow at the specified voltage and temperature.					
t <sub>rr</sub>	Reverse Recovery Time: The time interval between the instant the current passes through zero when changing from the forward direction to the reverse direction and a specified decay point after a peak reverse current occurs.					
V <sub>F</sub>	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current.					
$V_R$	Reverse Voltage: The reverse voltage dc value, no alternating component.					
$V_{RRM}$	Repetitive Peak Reverse Voltage: The peak reverse voltage including all repetitive transient voltages but excluding all non-repetitive transient voltages.					
$V_{RWM}$	Working Peak Reverse Voltage: The maximum peak voltage that can be applied over the operating temperature range excluding all transient voltages (ref JESD282-B). Also sometimes known as PIV.					

# **ELECTRICAL CHARACTERISTICS**

Туре	Maximum Forward Voltage V <sub>F</sub>		Maximum Reverse Current I <sub>R</sub>			Maximum Reverse Recovery Time	
	T <sub>C</sub> = 25°C	T <sub>C</sub> = 100°C	T <sub>C</sub> = 125°C	T <sub>C</sub> = 25°C	T <sub>c</sub> = 100°C	T <sub>C</sub> = 125°C	t <sub>rr</sub>
UES701	0.95 V		0.825 V	20 μΑ		4 mA	
UES702	@	N/A	@	@	N/A	@	35 ns <sup>(1)</sup>
UES703	$I_F = 25 \text{ A}$		$I_F = 25 \text{ A}$	$V_{RWM}$		V <sub>RWM</sub>	

**NOTES:** 1. Measured in circuit  $I_F = 0.5 \text{ A}$ ,  $I_R = 1 \text{ A}$ ,  $I_{REC} = 0.25 \text{ A}$ .



## **GRAPHS**

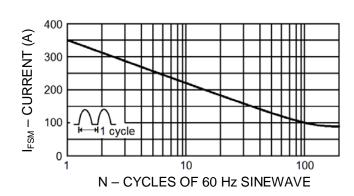


FIGURE 1

Maximum Forward Surge vs Number of Cycles

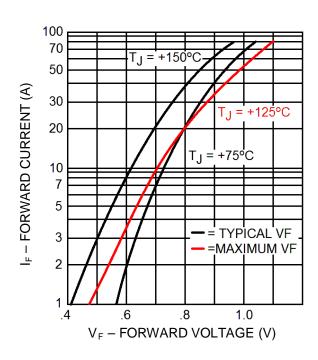


FIGURE 3
Forward Current vs. Forward Voltage

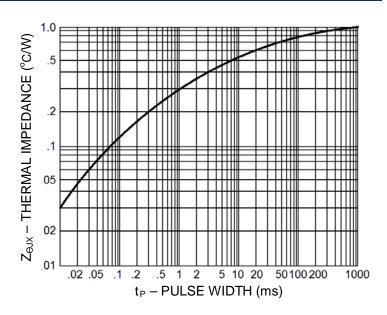


FIGURE 2
Thermal Impedance vs. Pulse Width

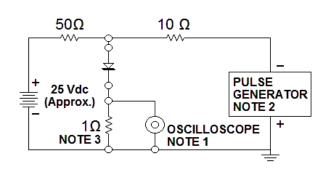


FIGURE 4
Reverse-Recovery Circuit

# **NOTES:**

- 1. Oscilloscope: Rise time  $\leq$  3 ns; input impedance = 50  $\Omega$ .
- 2. Pulse Generator: Rise time  $\leq$  8 ns; source impedance 10  $\Omega$ .
- 3. Current viewing resistor, non-inductive, coaxial recommend.



# **GRAPHS** (continued)

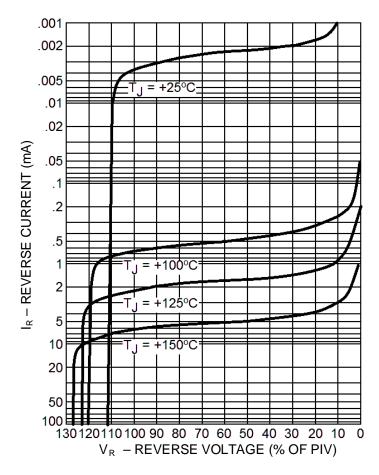


FIGURE 5
Typical Reverse Current vs. Reverse Voltage

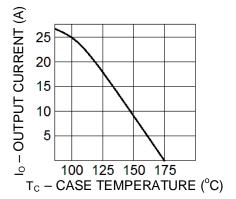
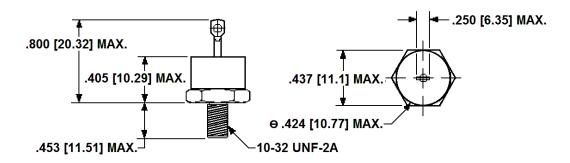


FIGURE 6
Output Current vs. Case Temperature



# PACKAGE DIMENSIONS



# **NOTES:**

- 1. Dimensions in inch [mm].
- 2. All metal surfaces tin-lead plated.
- 3. Maximum stud torque: 10 inch pounds.